| Thurs. 18 Nov. | Symposium Programme | |
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| 8:30-09:00 | Registration | |
| 9:00-09:30 | Welcome by the ESF | |
| | A. Helman: EuroGRAPHENE EUROCORES Programme | |
| 09:30-10:30 | Theory & properties: CONGRAN | Chair: V. Falko |
| | L. Covaci: Strained graphene Josephson junctions (30') | |
| | A. Jacobsen: Three-terminal junctions in graphene (15') | |
| | S. Dröscher: Quantum capacitance in graphene (15') | |
| 10:30-11:00 | Coffee break | |
| 11:00-12:00 | Theory & properties: ENTS | Chair: V. Falko |
| | P. Hakonen: Towards Entangled Spin Pairs in Graphene (30') | |
| | P. Recher: Creation of mobile spin-entangled electrons using superconductors (15') | |
| | M. Wimmer: Graphene edge states and spin detection (15') | |
| 12:00-13:00 | Novel devices and nanostructures: ELOGRAPH | |
| | U. Schwalke: Carbon for Nanoelectronics: From Nanotubes to Graphene (15') | |
| | J.P. Ginsel: CVD assisted fabrication of graphene layers for field effect device fabrication (15') | |
| | D. Pourfath: The effect of line edge roughness on electronic transport in graphene nanoribbons(15) |) |
| | T. Zimmer/Fregonese: A versatile compact model for ballistic 1D transistor: Applications to GNRFE | T and CNTFET (15') |
| 13:00-14:00 | Lunch | |
| 14:00-14:30 | Invited talk | Chair: C. Casiraghi |
| | V. Falko: Bilayer graphene under strain | |
| 14:30-15:30 | Hybrid and composite materials: SpinGraph | |
| | K. Horn: Electronic structure and many body effects in epitaxial graphene (30') | |
| | Y. Dedkov: Growth and electronic properties of graphene on metals (30') | |
| 15:30-16:30 | Hybrid and composite materials: GOSPEL | |
| | V. Palermo: The supramolecular chemistry of graphenes: introduction to GOSPEL project (10') | |
| | A. Liscio: Graphene-organic composites for field-effect transistors (25') | |
| | Y. Hernandez: Chemical Synthesis of Graphene and Graphene Nanoribbons (25') | |
| 16:30-17:00 | Coffee break | |
| 17:00 | Invited talks (open) | Chair : P. Samori |
| 17:00-17:45 | J. Hone, Columbia University, US | |
| 17:45-18:30 | L. Colombo, Texas Instruments, US | |
| 20:00 | Symposium dinner – 'Maison Kammerzell' | |
| Fri. 19 Nov. | | |
| 9-9:30 | T. Seyller: DFG priority programme on Graphene (30') | Chair : U. Schwalke |
| 9:30-10:00 | A. Isacsson: EC project RODIN (30') | |
| 10:00-10:30 | Discussion on joint activities and synergies | |
| 10:30-11:00 | Coffee break | |
| 11:00-12:00 | Graphene on SiC : EPIGRAT | |
| | E. Janzén: Introduction to EPItaxial GRAphene Transistor (15') | |
| | C. Virojanadara: Characterization and functionalization of epitaxial graphene on SiC (10') | |
| | J. Baranowski: Growth and characterization of Epitaxial Graphene (20') | |
| | N. Rorsman: Device activities in EPIGRAT (15') | |
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| 12:00-13:00 | Graphene on SiC : GRAPHIC-RF | |
| 12:00-13:00 | V. Raineri: Graphene on SiC for high frequency devices: introduction to GRAPHIC-RF project (15') | |
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